





FMMT558

May 2011

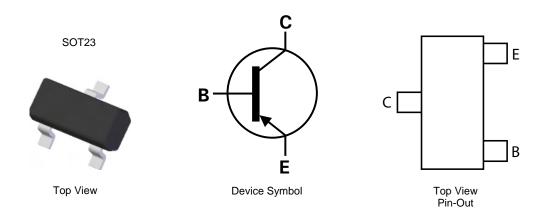
400V PNP SILICON PLANAR HIGH VOLTAGE TRANSISTOR IN SOT23

Features

- 500mW Power dissipation
- 150mA Continuous collector current
- 500mA Peak Pulse Current
- Excellent hFE Characteristics Up To 100mA
- Low Saturation Voltage
- Complementary part number FMMT458
- Totally Lead-Free & Fully RoHS compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT23
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT558TA	AEC-Q101	558	7	8	3,000
FMMT558QTA	Automotive	558	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com.

Marking Information





FMMT558

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-400	V
Collector-Emitter Voltage	V_{CEO}	-400	V
Emitter-Base Voltage	V _{EBO}	-5	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I _{CM}	-500	mA
Base Current	I _B	-200	mA

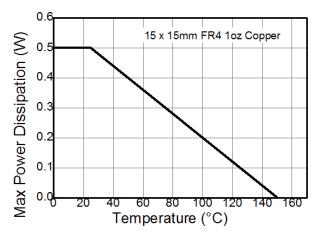
Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ hetaJA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 7)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C

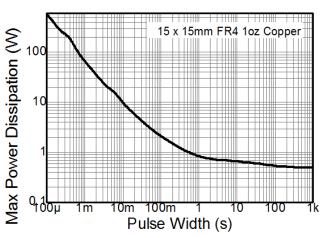
Notes:

- 6. For a device surface mounted on 15mm X 15mm X 1.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

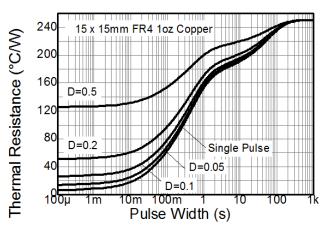
Thermal Characteristics and Derating information



Derating Curve



Pulse Power Dissipation



Transient Thermal Impedance





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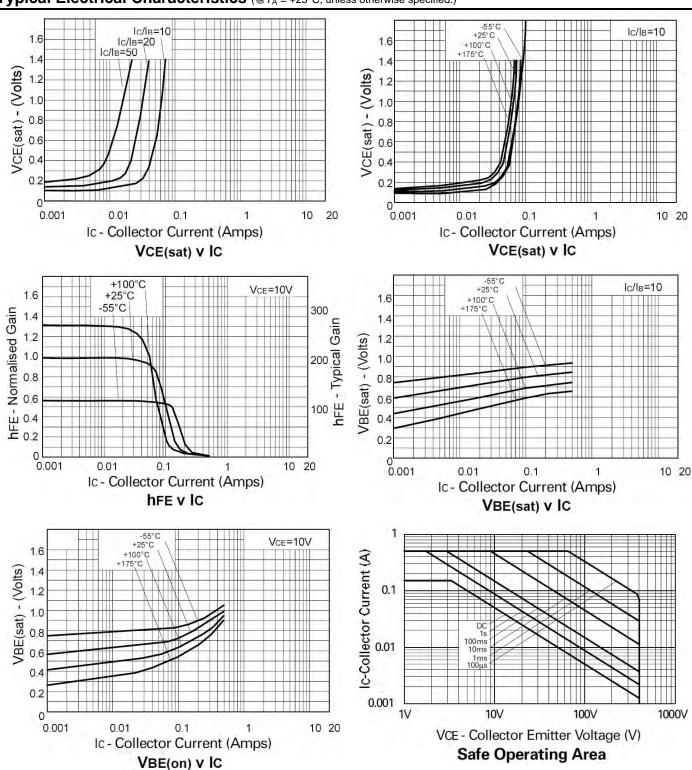
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-400	-	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	-400	-	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	-	-	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	-	-	-100	nA	V _{CB} = -320V
Emitter Cutoff Current	I _{EBO}	-	-	-100	nA	V _{EB} = -4V
Collector Emitter Cutoff Current	I _{CES}	-	-	-100	nA	V _{CE} = -320V
Static Forward Current Transfer Ratio (Note 8)	h _{FE}	100 100 15	- - -	300 -	-	$I_C = -1mA$, $V_{CE} = -10V$ $I_C = -50mA$, $V_{CE} = -10V$ $I_C = -100mA$, $V_{CE} = -10V$
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}	-	-	-200 -500	mV mV	$I_C = -20mA$, $I_B = -2mA$ $I_C = -50mA$, $I_B = -6mA$
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(on)}	-	-	-0.9	V	I _C = -50mA, V _{CE} = -10V
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}	-	-	-0.9	V	$I_C = -50 \text{mA}, I_B = -5 \text{mA}$
Output Capacitance	C _{obo}	-	-	5	pF	V _{CB} = -20V, f = 1MHz
Transition Frequency	f _T	50	-	-	MHz	V _{CE} = -20V, I _C = -10mA, f = 20MHz
Turn-On Time	t _{on}	-	95	-	ns	$V_{CE} = -100V, I_{C} = -50mA$
Turn-Off Time	t _{off}	-	1600	-	ns	$I_{B1} = 5mA, I_{B2} = -10mA$

Notes: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%



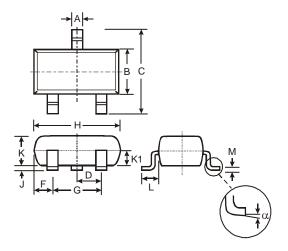
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

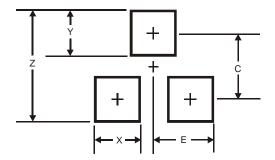
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
M	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
Е	1.35





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